NSN 5961-01-463-9111

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-463-9111 **Inclosure Material:** Metal **Overall Length:** 0.855 inches **Terminal Length:** 0.800 inches **Overall Width:** 0.545 inches **End Application:** C-17aacfte/ifscm89954 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage and 100.0 drain to gate voltage and 20.0 drain to substrate voltage **Current Rating Per Characteristic:** 75.00 amperes repetitive peak forward current peak and 300.00 amperes forward current, average any acceptable **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 1 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No